

## SiC Schottky Barrier Diode

## TRS10A65F

## FEATURES

- Forward DC current  
 $I_{F(DC)} = 10\text{ A}$
- Repetitive peak reverse voltage  
 $V_{RRM} = 650\text{ V}$
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## APPLICATIONS

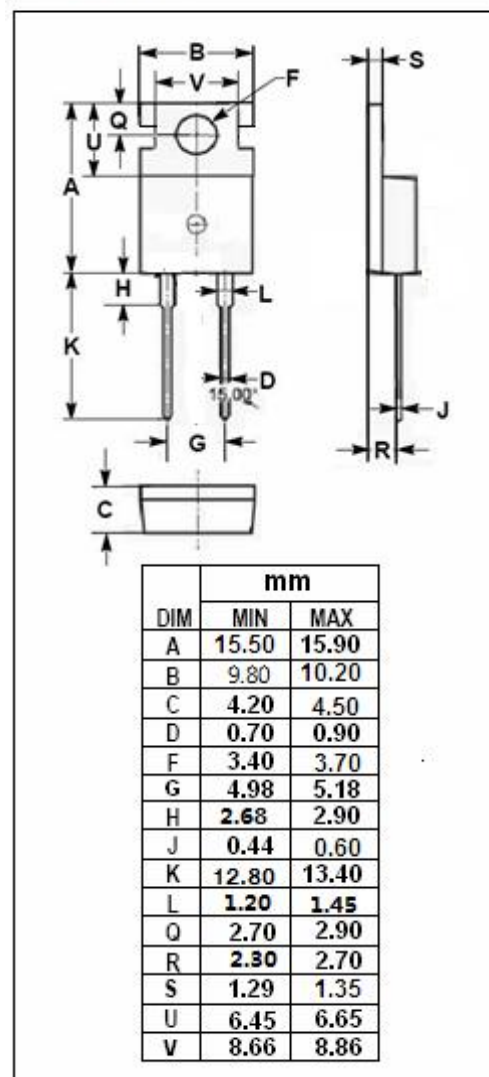
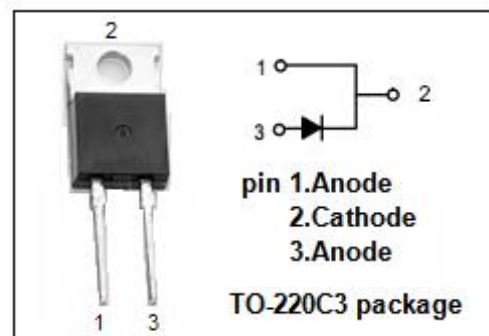
- DC-DC Converters
- Uninterruptible Power Supplies
- Solar Inverters
- Power Factor Correction

ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ\text{C}$ )

SYMBOL	PARAMETER	VALUE	UNIT
$V_{RRM}$	Peak Repetitive Reverse Voltage	650	V
$I_{F(DC)}$	Forward DC current	10	A
$T_J$	Junction Temperature	175	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55~175	$^\circ\text{C}$

## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	3.92	$^\circ\text{C/W}$



**SiC Schottky Barrier Diode****TRS10A65F****ELECTRICAL CHARACTERISTICS** (Pulse Test: Pulse Width=300 μs, Duty Cycle ≤ 1%)

SYMBOL	PARAMETER	CONDITIONS	MAX	UNIT
$V_F$	Maximum Instantaneous Forward Voltage	$I_F = 10A$ ; $T_J = 25^\circ C$	1.7	V
$I_R$	Maximum Instantaneous Reverse Current	$V_R = V_{RRM}$ , $T_J = 25^\circ C$	90	μA

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